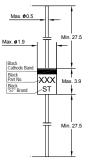
Silicon Epitaxial Planar Switching Diode

Features

- Fast switching speed
- High reliability



Glass Case DO-35 Dimensions in mm

Absolute Maximum Ratings (T _a = 25 °C)			
Parameter	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	V _{RM}	100	V
Reverse Voltage	V _R	75	V
Average Rectified Forward Current 1N914 1N914A / E	B I _{F(AV)}	75 200	mA
Forward Continuous Current 1N914 1N914A / E	B I _{FM}	150 300	mA
Non-Repetitive Peak Forward Surge Current at t = 1 s 1N914 at t = 1 µs 1N914A / B at t = 1 µs	I _{FSM}	1 1 4	А
Power Dissipation	P _{tot}	500	mW
Operating and Storage Temperature Range	T _j ,T _{stg}	- 65 to + 175	°C

Characteristics at T_a = 25 °C

Characteristics at T _a = 25 °C					
Parameter		Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 5 \text{ mA}$ at $I_F = 100 \text{ mA}$ at $I_F = 10 \text{ mA}$ at $I_F = 20 \text{ mA}$	1N914B 1N914B 1N914 1N914	V _F	0.62 - - -	0.72 1 1 1	V
Reverse Current at $V_R = 20 V$ at $V_R = 75 V$ at $V_R = 20 V$, $T_j = 150 $ °C		I _R		25 5 50	nΑ μΑ μΑ
Diode Capacitance at $V_R = 0$, f = 1 MHz		Cj	-	4	pF
Reverse Recovery Time at I_F = 10 mA to I_R = 1 mA, V_R = 6 V, R_L = 100 Ω		t _{rr}	-	4	ns

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